

Features

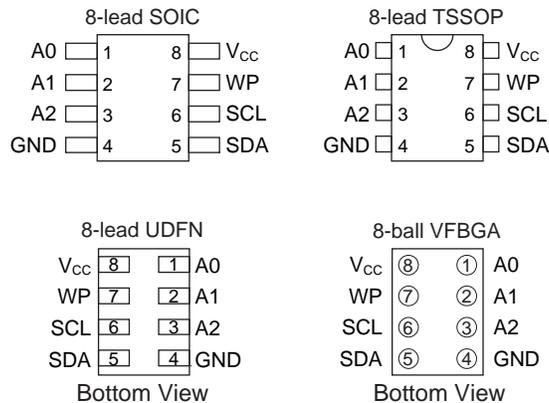
- Low-voltage and standard-voltage operation
 - $V_{cc} = 1.7V$ to 5.5V
- Internally organized as 32,768 x 8
- Two-wire serial interface
- Schmitt Trigger, filtered inputs for noise suppression
- Bidirectional data transfer protocol
- 1MHz (5.0V, 2.7V, 2.5V), and 400kHz (1.7V) compatibility
- Write protect pin for hardware and software data protection
- 64-byte page write mode (partial page writes allowed)
- Self-timed write cycle (5ms max)
- High reliability
 - Endurance: one million write cycles
 - Data retention: 40 years
- Lead-free/Halogen-free devices available
- 8-lead JEDEC SOIC, 8-lead TSSOP, 8-lead UDFN and 8-ball VFBGA packages
- Die sales: wafer form, waffle pack and bumped wafers

Description

The Atmel® AT24C256C provides 262,144-bits of serial electrically erasable and programmable read-only memory (EEPROM) organized as 32,768 words of eight bits each. The device's cascading feature allows up to eight devices to share a common two-wire bus. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The devices are available in space-saving 8-lead JEDEC SOIC, 8-lead TSSOP, 8-lead UDFN, and 8-ball VFBGA packages. In addition, this device operates from 1.7V to 5.5V.

Table 1. Pin Configurations

Pin Name	Function
A0 – A2	Address Inputs
SDA	Serial Data
SCL	Serial Clock Input
WP	Write Protect
GND	Ground



Two-wire Serial EEPROM

256K (32,768 x 8)

Atmel AT24C256C

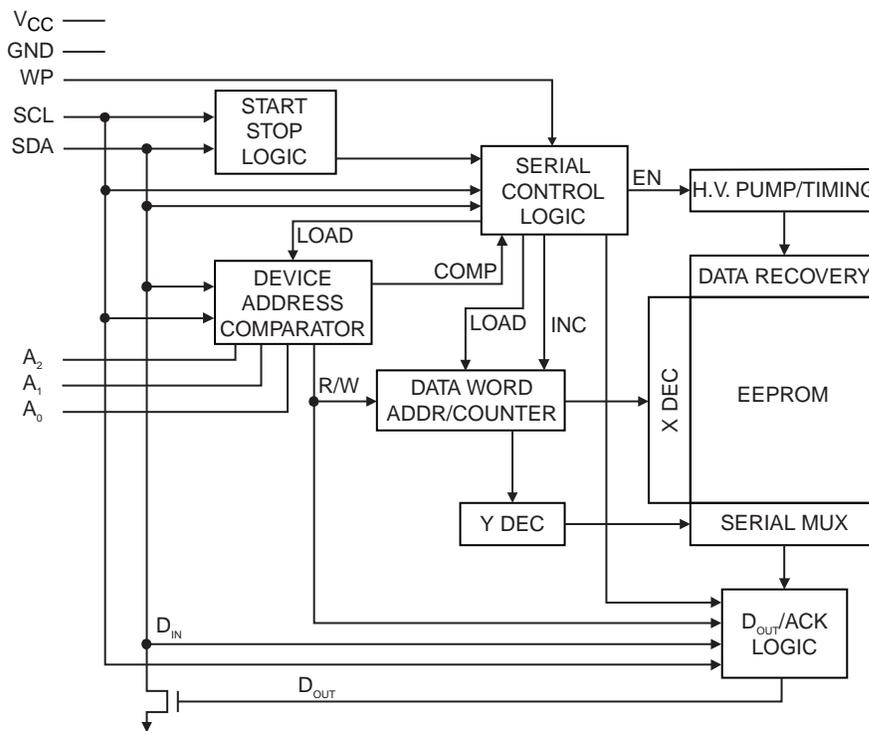


1. Absolute Maximum Ratings*

Operating temperature	-55°C to +125°C
Storage temperature	-65°C to + 150°C
Voltage on any pin with respect to ground	- 1.0 V +7.0V
Maximum operating voltage	6.25V
DC output current	5.0mA

*NOTICE: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 1-1. Block Diagram



2. Pin Descriptions

SERIAL CLOCK (SCL): The SCL input is used to positive-edge clock data into each EEPROM device and negative-edge clock data out of each device.

SERIAL DATA (SDA): The SDA pin is bidirectional for serial data transfer. This pin is open drain driven and may be wire-ORed with any number of other open-drain or open-collector devices.

DEVICE/PAGE ADDRESSES (A2, A1, A0): The A2, A1, and A0 pins are device address inputs that are hardwired (directly to GND or to V_{CC}) for compatibility with other Atmel AT24Cxx devices. When the pins are hardwired, as many as eight 256K devices may be addressed on a single bus system. (Device addressing is discussed in detail under “[Device Addressing](#)”) A device is selected when a corresponding hardware and software match is true. If these pins are left floating, the A2, A1, and A0 pins will be internally pulled down to GND. However, due to capacitive coupling that may appear during customer applications, Atmel recommends always connecting the address pins to a known state. When using a pull-up resistor, Atmel recommends using 10k Ω or less.

WRITE PROTECT (WP): The write protect input, when connected to GND, allows normal write operations. When WP is connected directly to V_{CC} , all write operations to the memory are inhibited. If the pin is left floating, the WP pin will be internally pulled down to GND. However, due to capacitive coupling that may appear during customer applications, Atmel recommends always connecting the WP pins to a known state. When using a pull-up resistor, Atmel recommends using 10k Ω or less.



3. Memory Organization

Atmel AT24C256C, 256K SERIAL EEPROM: The 256K is internally organized as 512 pages of 64-bytes each. Random word addressing requires a 15-bit data word address.

Table 3-1. Pin Capacitance⁽¹⁾

Applicable over recommended operating range from: TA = 25°C, f = 1.0MHz, V_{CC} = +1.7V

Symbol	Test Condition	Max	Units	Conditions
C _{I/O}	Input/Output Capacitance (SDA)	8	pF	V _{I/O} = 0V
C _{IN}	Input Capacitance (A0, A1, SCL)	6	pF	V _{IN} = 0V

Note: 1. This parameter is characterized and is not 100% tested

Table 3-2. DC Characteristics

Applicable over recommended operating range from: T_{A1} = -40°C to +85°C, V_{CC} = +1.7V to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Typ	Max	Units
V _{CC1}	Supply Voltage			1.7		5.5	V
I _{CC1}	Supply Current	V _{CC} = 5.0V	Read at 400kHz		1.0	2.0	mA
I _{CC2}	Supply Current	V _{CC} = 5.0V	Write at 400kHz		2.0	3.0	mA
I _{SB1}	Standby Current (1.7V option)	V _{CC} = 1.7V	V _{IN} = V _{CC} or V _{SS}			1.0	μA
		V _{CC} = 5.0V				6.0	μA
I _{LI}	Input Leakage Currentt V _{CC} = 5.0V	V _{IN} = V _{CC} or V _{SS}			0.10	3.0	μA
I _{LO}	Output Leakage Currentt V _{CC} = 5.0V	V _{OUT} = V _{CC} or V _{SS}			0.05	3.0	μA
V _{IL}	Input Low Level ⁽¹⁾			-0.6		V _{CC} x 0.3	V
V _{IH}	Input High Level ⁽¹⁾			V _{CC} x 0.7		V _{CC} + 0.5	V
V _{OL2}	Output Low Level	V _{CC} = 3.0V	I _{OL} = 2.1mA			0.4	V
V _{OL1}	Output Low Level	V _{CC} = 1.7V	I _{OL} = 0.15mA			0.2	V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested

Table 3-3. AC Characteristics (Industrial Temperature)

Applicable over recommended operating range from:

$T_{AI} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = +1.7\text{V}$ to $+5.5\text{V}$, $CL = 100\text{ pF}$ (unless otherwise noted). Test conditions are listed in Note 2.

Symbol	Parameter	1.7V		2.5, 5.0V		Units
		Min	Max	Min	Max	
f_{SCL}	Clock Frequency, SCL		400		1000	kHz
t_{LOW}	Clock Pulse Width Low	1.3		0.4		μs
t_{HIGH}	Clock Pulse Width High	0.6		0.4		μs
t_i	Noise Suppression Time ⁽¹⁾		100		50	ns
t_{AA}	Clock Low to Data Out Valid	0.05	0.9	0.05	0.55	μs
t_{BUF}	Time the bus must be free before a new transmission can start ⁽¹⁾	1.3		0.5		μs
$t_{HD,STA}$	Start Hold Time	0.6		0.25		μs
$t_{SU,STA}$	Start Set-up Time	0.6		0.25		μs
$t_{HD,DAT}$	Data In Hold Time	0		0		μs
$t_{SU,DAT}$	Data In Set-up Time	100		100		ns
t_R	Inputs Rise Time ⁽¹⁾		0.3		0.3	μs
t_F	Inputs Fall Time ⁽¹⁾		300		100	ns
$t_{SU,STO}$	Stop Set-up Time	0.6		0.25		μs
t_{OH}	Data Out Hold Time	50		50		ns
t_{WR}	Write Cycle Time		5		5	ms
Endurance ⁽¹⁾	25°C, Page Mode, 3.3V	1,000,000				Write Cycles

Note: 1. This parameter is ensured by characterization and is not 100% tested

2. AC measurement conditions:

- R_L (connects to V_{CC}): 1.3k Ω (2.5V, 5.5V), 10k Ω (1.7V)
- Input pulse voltages: 0.3 V_{CC} to 0.7 V_{CC}
- Input rise and fall times: $\leq 50\text{ns}$
- Input and output timing reference voltages: 0.5 V_{CC}

SOFTWARE RESET: After an interruption in protocol, power loss or system reset, any 2-wire part can be protocol reset by following these steps:

- a) Create a start bit condition,
- b) Clock nine cycles,
- c) Create another start bit followed by stop bit condition as shown below.

The device is ready for next communication after above steps has been completed.

Figure 4-3. Software Reset

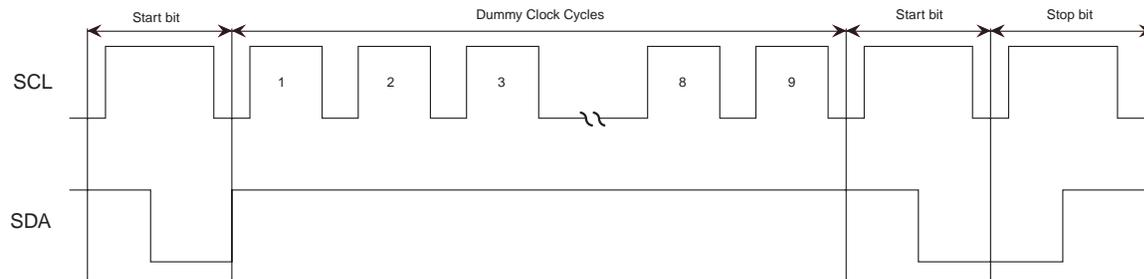


Figure 4-4. Bus Timing

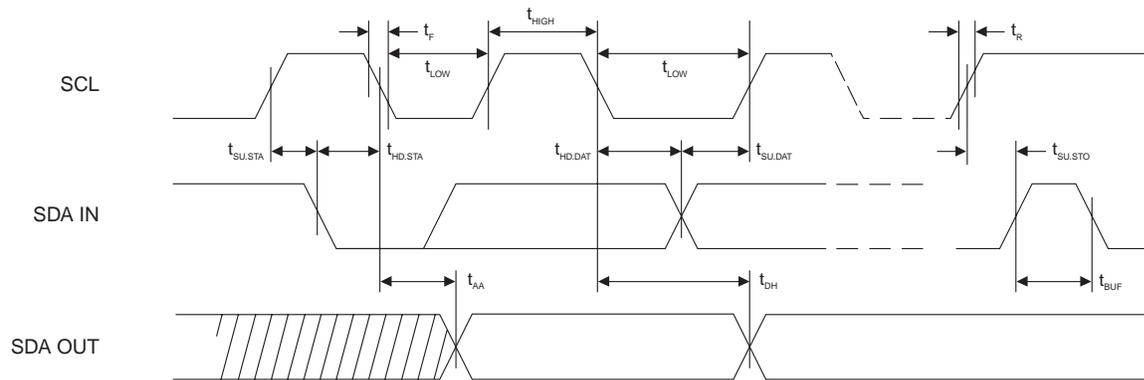
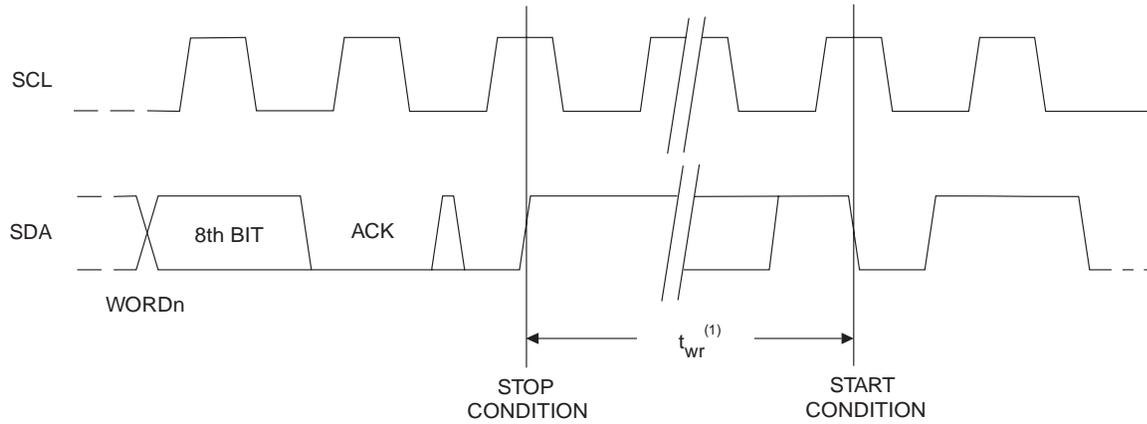
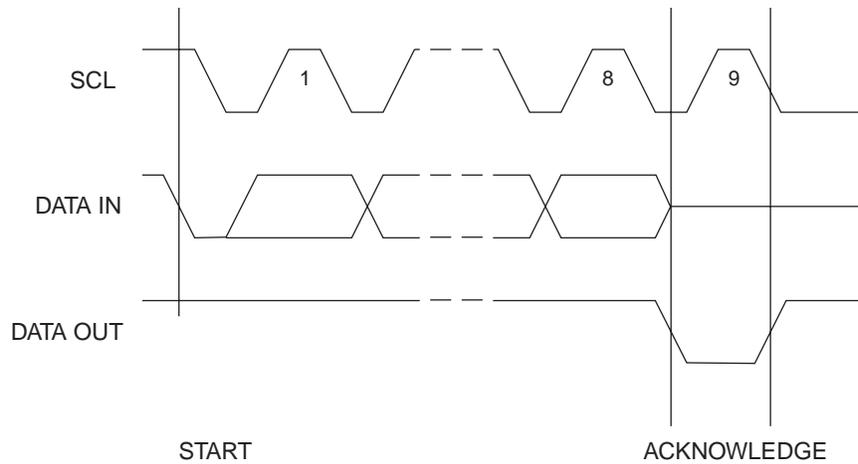


Figure 4-5. Write Cycle Timing



Note: 1. The write cycle time t_{wr} is the time from a valid stop condition of a write sequence to the end of the internal clear/write cycle

Figure 4-6. Output Acknowledge



5. Device Addressing

The 256K EEPROM requires an 8-bit device address word following a start condition to enable the chip for a read or write operation (refer to Figure 5-1). The device address word consists of a mandatory “1”, “0” sequence for the first four most significant bits as shown. This is common to all two-wire EEPROM devices.

Figure 5-1. Device Addressing

1	0	1	0	A2	A1	A0	R/W
MSB				LSB			

The next three bits are the A2, A1, A0 device address bits to allow as many as eight devices on the same bus. These bits must compare to their corresponding hardwired input pins. The A2, A1, and A0 pins use an internal proprietary circuit that biases them to a logic low condition if the pins are allowed to float.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high, and a write operation is initiated if this bit is low.

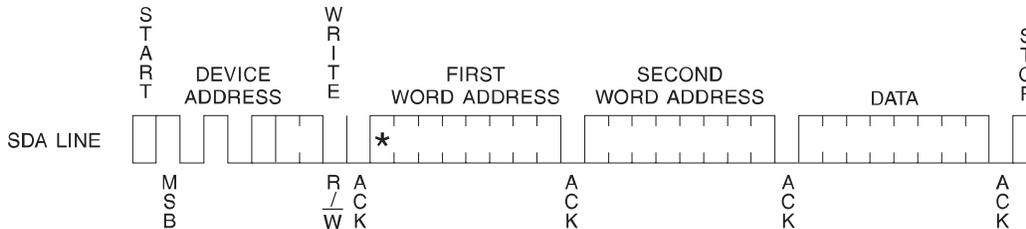
Upon a compare of the device address, the EEPROM will output a “0”. If a compare is not made, the device will return to a standby state.

DATA SECURITY: The Atmel® AT24C256C has a hardware data protection scheme that allows the user to write protect the whole memory when the WP pin is at V_{CC} .

6. Write Operations

BYTE WRITE: A write operation requires two 8-bit data word addresses following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a “0” and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a “0”. The addressing device, such as a microcontroller, must then terminate the write sequence with a stop condition. At this time the EEPROM enters an internally-timed write cycle, t_{WR} , to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the write is complete (refer to Figure 6-1).

Figure 6-1. Byte Write

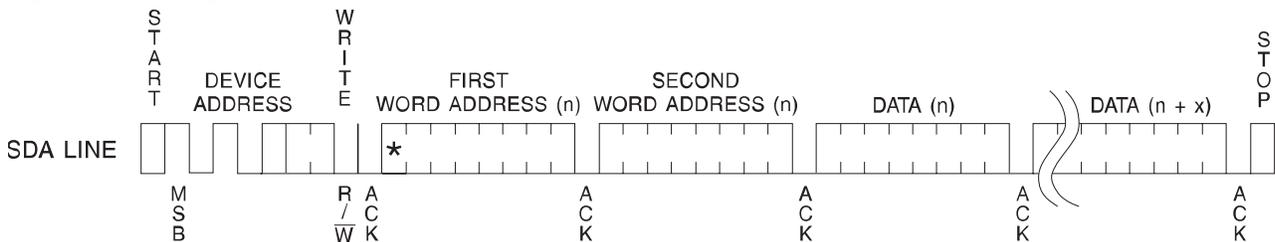


Note: * = DON'T CARE bit

PAGE WRITE: The 256K EEPROM is capable of 64-byte page writes.

A page write is initiated the same way as a byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to 63 more data words. The EEPROM will respond with a “0” after each data word received. The microcontroller must terminate the page write sequence with a stop condition (refer to Figure 6-2).

Figure 6-2. Page Write



Note: * = DON'T CARE bit

The data word address lower six bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than 64 data words are transmitted to the EEPROM, the data word address will “roll over” and previous data will be overwritten. The address “roll over” during write is from the last byte of the current page to the first byte of the same page.

ACKNOWLEDGE POLLING: Once the internally-timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a “0”, allowing the read or write sequence to continue.

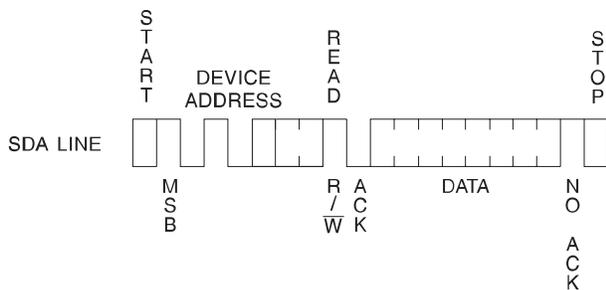
7. Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to “1”. There are three read operations: current address read, random address read, and sequential read.

CURRENT ADDRESS READ: The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address “roll over” during read is from the last byte of the last memory page, to the first byte of the first page.

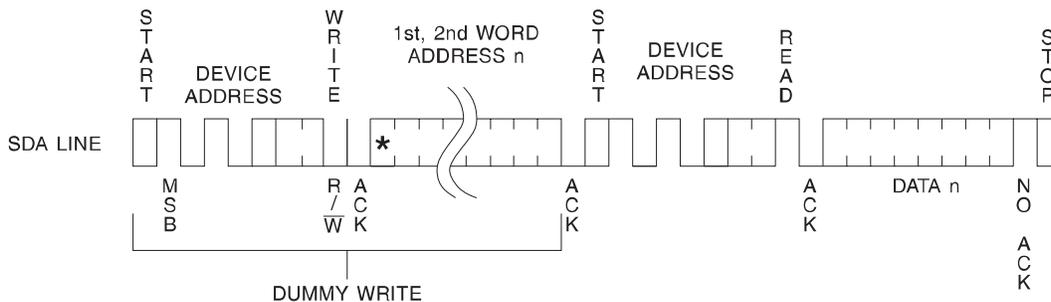
Once the device address with the read/write select bit set to “1” is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input “0” but does generate a following stop condition (refer to Figure 7-1).

Figure 7-1. Current Address Read



RANDOM READ: A random read requires a “dummy” byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a “0” but does generate a following stop condition. (Refer to Figure 7-2)

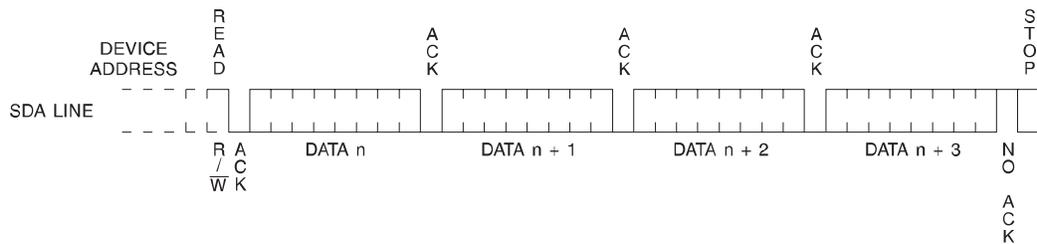
Figure 7-2. Random Read



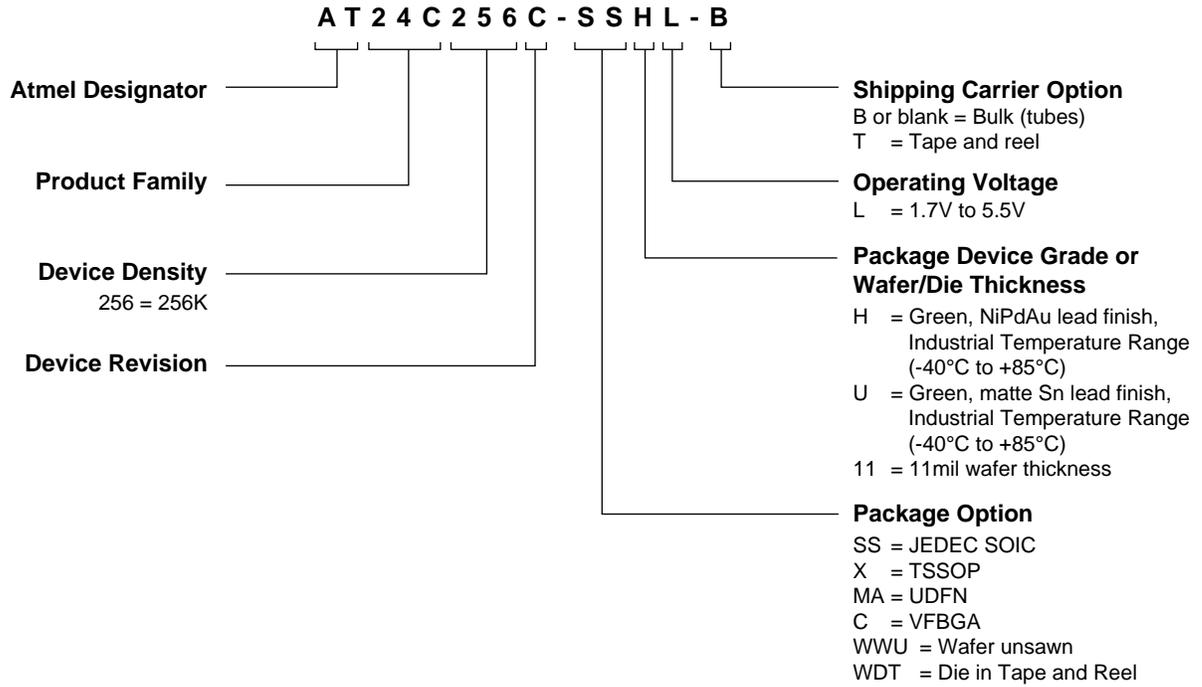
Note: * = DON'T CARE bit

SEQUENTIAL READ: Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will “roll over” and the sequential read will continue. The sequential read operation is terminated when the microcontroller does not respond with a “0” but does generate a following stop condition (refer to Figure 7-3).

Figure 7-3. Sequential Read



8. Ordering Code Detail



9. Part Markings

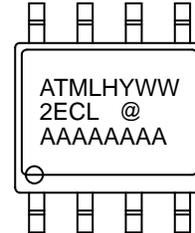
8 lead TSSOP

3 Rows
2 of 6 and 1 of 7 Characters



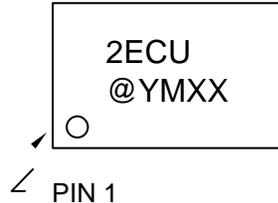
8 lead SOIC

3 Rows of 8 Characters



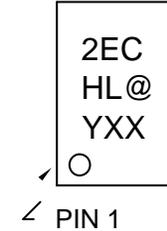
8-ball VFBGA - 2.35x3.73mm

2 Rows
1 of 4 and 1 of 5 Characters



8 lead DFN - 2.0x3.0mm

3 Rows of 3 Characters



Catalog Number: AT24C256C

Catalog Truncation: 2EC

Date Codes			Voltages
Y = Year	M = Month	WW = Work Week of Assembly	L: 1.8v min
0: 2010 4: 2014	A: January	02: Week 2	
1: 2011 5: 2015	B: February	04: Week 4	
2: 2012 6: 2016	" " "	" " "	
3: 2013 7: 2017	L: December	52: Week 52	
Trace Code			Grade/Lead Finish Material
XX = Trace Code (ATMEL Lot Numbers to Correspond Code) (e.g. XX: AA, AB...YZ, ZZ)			U: Industrial/Matt Tin H: Industrial/NiPdAu
Lot Number			ATMEL Truncation
AAAAAAA = ATMEL Wafer Lot Number			AT: ATMEL ATM: ATMEL ATML: ATMEL
Location of Assembly			
@ = Location of Assembly			

Note: Packages are not to scale in comparison to each other.

3/28/11



Package Mark Contact:
DL-CSO-Assy_eng@atmel.com

TITLE

24C256CSM, AT24C256C Standard Marking Information
for Package Offering

DRAWING NO.

24C256CSM

REV.

B

10. Ordering Codes

Atmel AT24C256C Ordering Information

Ordering Code	Voltage	Package	Operating Range
AT24C256C-SSHL-B ⁽¹⁾	1.7V to 5.5V	8S1	Lead-free/Halogen-free Industrial Temperature (-40°C to 85°C)
AT24C256C-SSHL-T ⁽²⁾	1.7V to 5.5V	8S1	
AT24C256C-XHL-B ⁽¹⁾	1.7V to 5.5V	8X	
AT24C256C-XHL-T ⁽²⁾	1.7V to 5.5V	8X	
AT24C256C-MAHL-T ⁽²⁾	1.7V to 5.5V	8MA2	
AT24C256C-CUL-T ⁽²⁾	1.7V to 5.5V	8U2-1	
AT24C256C-WWU11L ⁽³⁾	1.7V to 5.5V	Die Sale	Industrial Temperature (-40°C to 85°C)

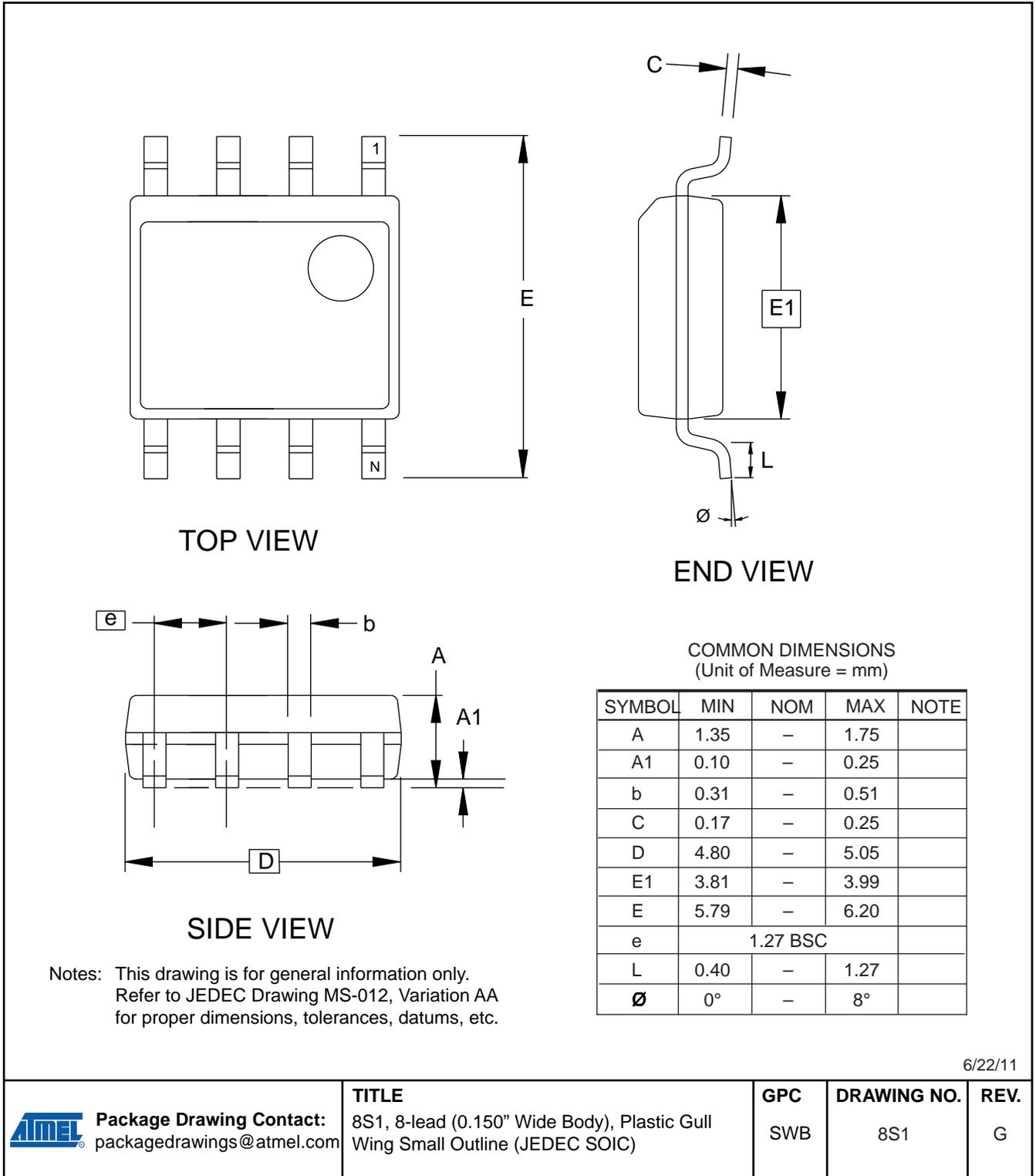
- Note:**
1. Bulk delivery in tubes (SOIC and TSSOP 100/tube)
 2. Tape and reel delivery (SOIC 4k/reel, TSSOP, UDFN and VFBGA 5k/reel)
 3. Contact Atmel Sales for Wafer sales

Package Type	
8S1	8-lead, 0.150" Wide, Plastic Gull Wing Small Outline Package (JEDEC SOIC)
8X	8-lead, 4.40mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)
8MA2	8-lead, 2.00mm x 3.00mm Body, 0.50mm Pitch, Dual No Lead Package (UDFN)
8U2-1	8-ball, die Ball Grid Array Package (VFBGA)



11. Packaging Information

8S1 – JEDEC SOIC



6/22/11



Package Drawing Contact:
packagedrawings@atmel.com

TITLE

8S1, 8-lead (0.150" Wide Body), Plastic Gull Wing Small Outline (JEDEC SOIC)

GPC

SWB

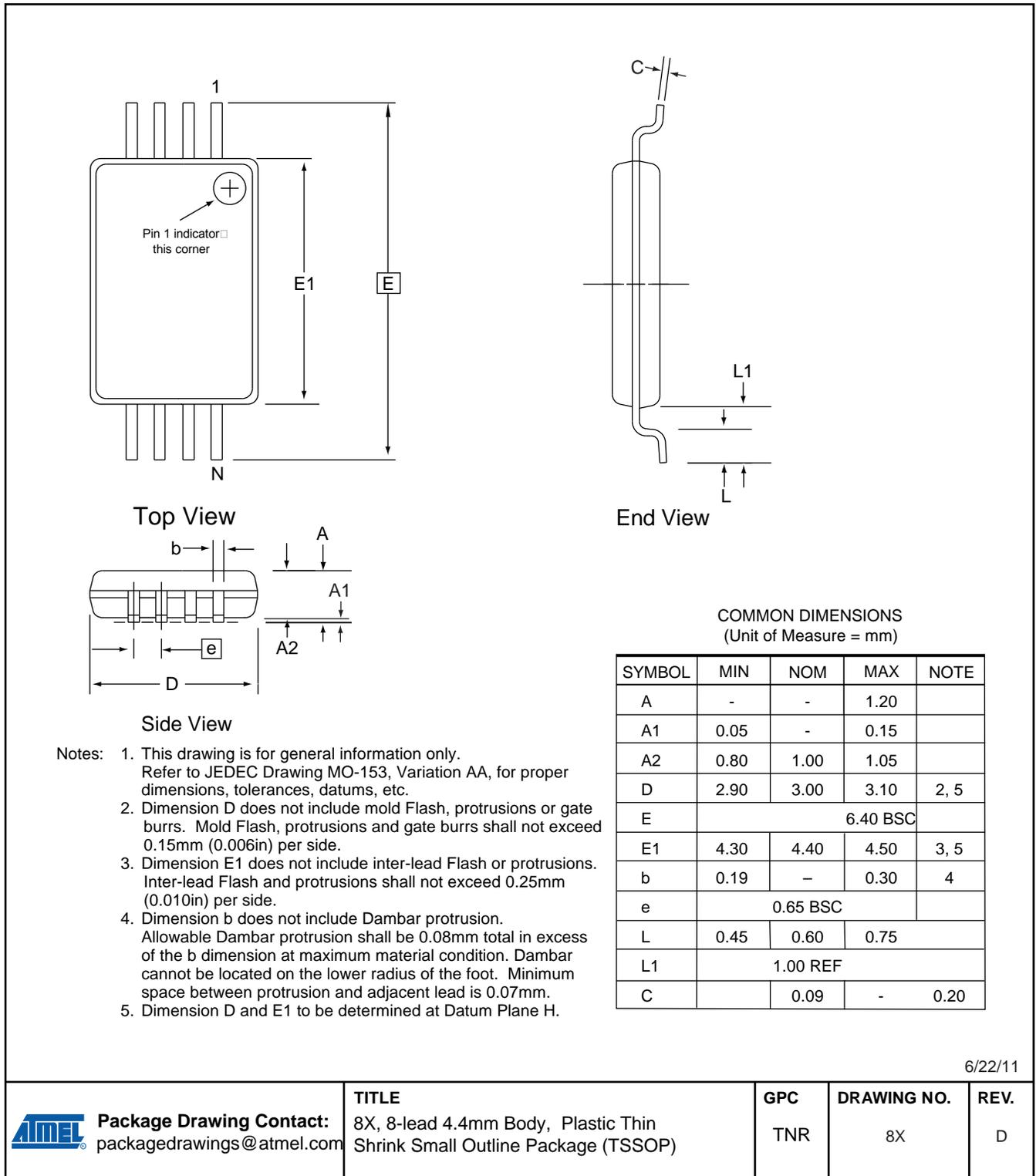
DRAWING NO.

8S1

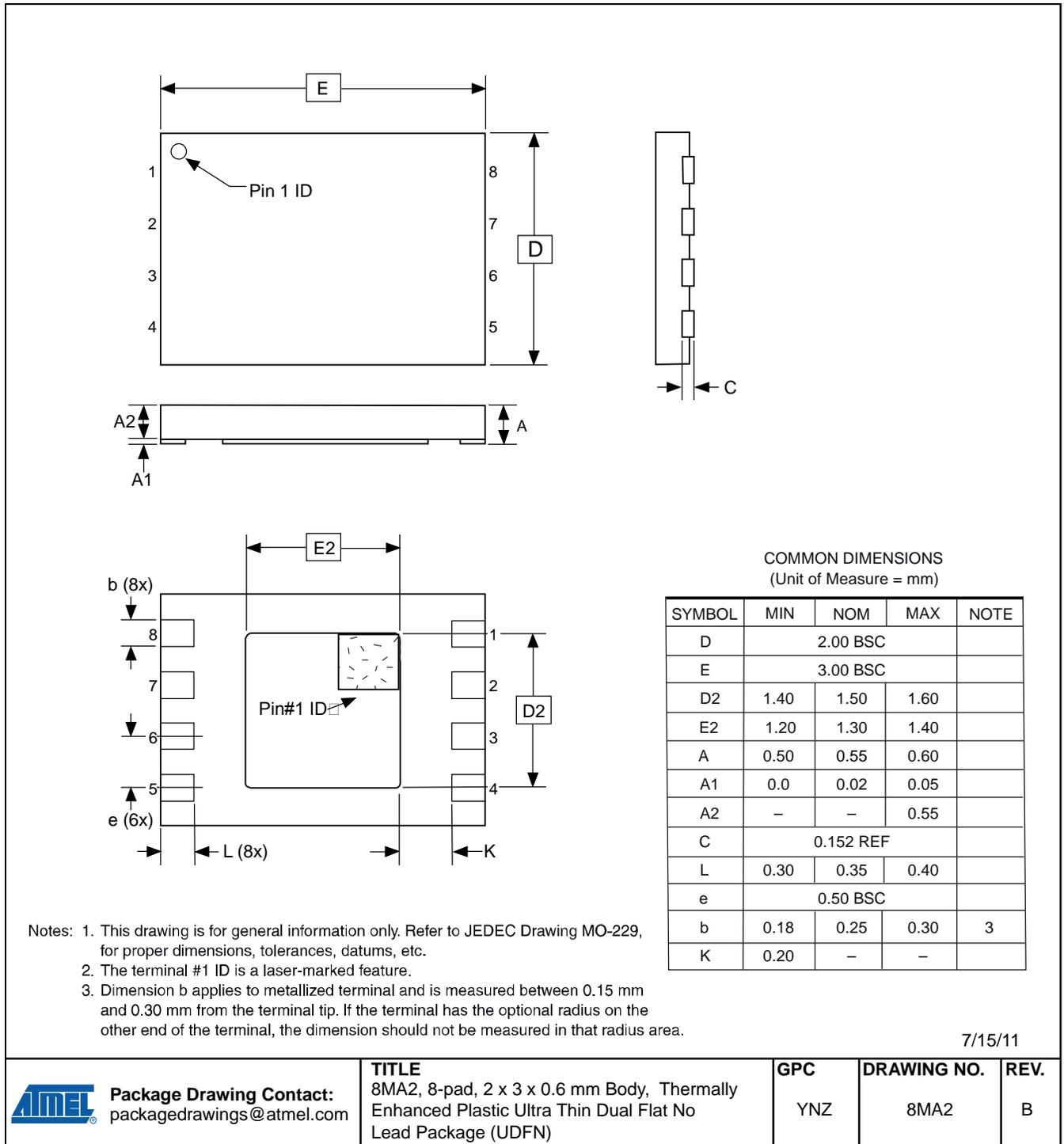
REV.

G

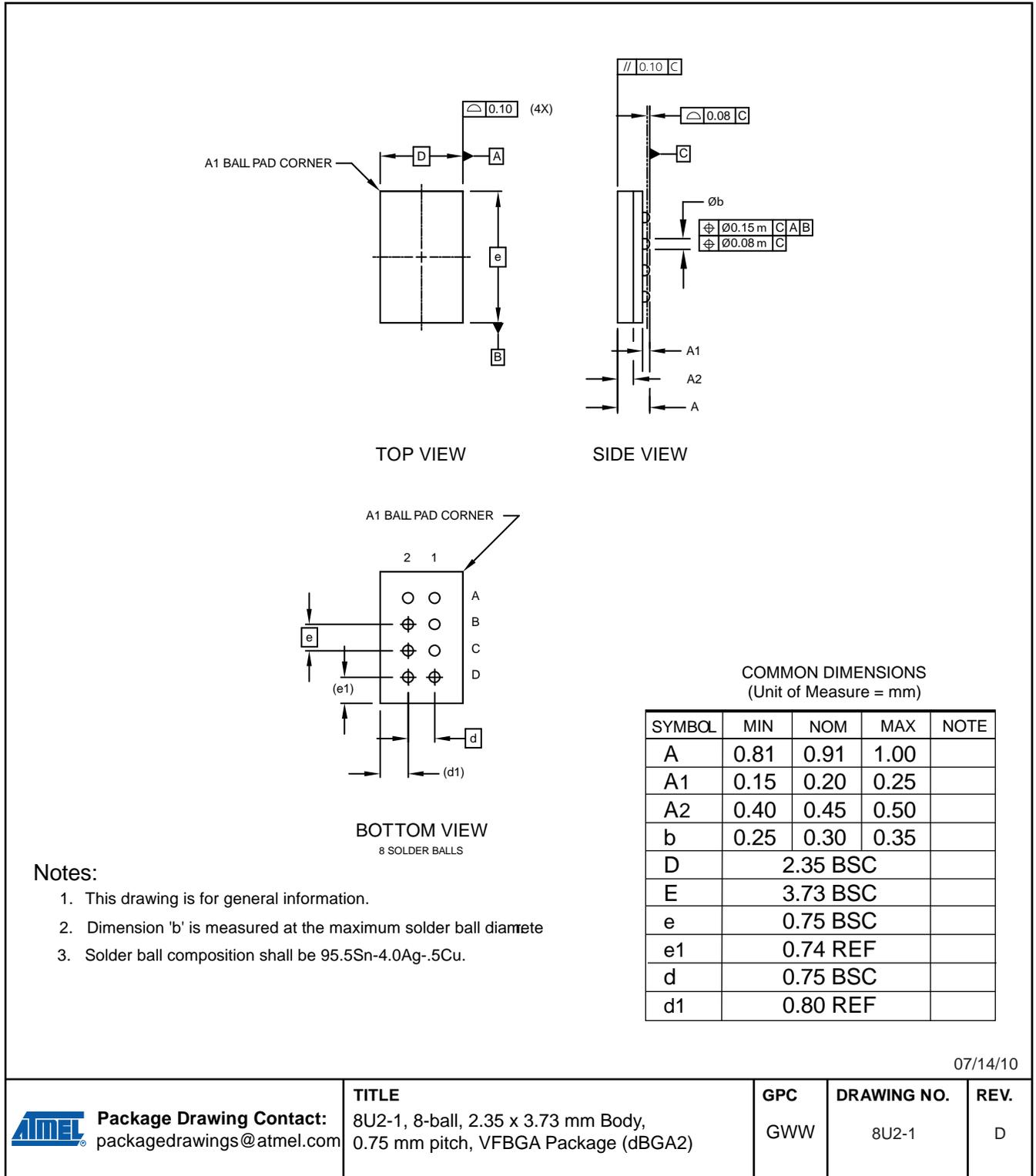
8X – TSSOP



8MA2 – UDFN



8U2-1 – VFBGA





Appendix A. Revision History

Doc. Rev.	Date	Comments
8568D	09/2011	Atmel global device marking alignment Update 8S1, 8A2 to 8X, 8MA2, and 8U2-1 package drawings
8568C	05/2010	Update 8S1 and 8A2 package drawings.
8568B	03/2010	Part Markings and ordering detail/codes updated.
8568A	09/2009	Initial document release

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